

DGG OR DL PACKAGE

SCES046G-JULY 1995-REVISED OCTOBER 2004

### **FEATURES**

- Member of the Texas Instruments Widebus™ Family
- **EPIC™** (Enhanced-Performance Implanted **CMOS) Submicron Process**
- ESD Protection Exceeds 2000 V Per MIL-STD-883. Method 3015: Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages

## DESCRIPTION

This 12-bit to 24-bit multiplexed D-type latch is designed for 1.65-V to 3.6-V V<sub>CC</sub> operation.

The SN74ALVCH16260 is used in applications in which two separate data paths must be multiplexed onto, or demultiplexed from, a single data path. Typical applications include multiplexing and/or demultiplexing address and data information in microprocessor or bus-interface applications. This device also is useful in memory-interleaving applications.

Three 12-bit I/O ports (A1-A12, 1B1-1B12, and 2B1-2B12) are available for address and/or data transfer. The output-enable (OE1B, OE2B, and OEA) inputs control the bus transceiver functions. The OE1B and OE2B control signals also allow bank control in the A-to-B direction.

	(TOP VI	EW	)
			h
OEA	1	56	OE2B
LE1B	2	55	LEA2B
2B3 [	3	54	2B4
GND [	4	53	GND
2B2	5	52	2B5
2B1	6	51	2B6
Vcc	7	50	Vcc
A1 [	8	49	2B7
A2 [	9	48	2B8
A3 [	10	47	2B9
GND [	11	46	] GND
A4 [	12	45	2B10
A5 [	13	44	2B11
A6 [	14	43	2B12
A7 [	15	42	] 1B12
A8 [	16	41	] 1B11
A9 [	17	40	] 1B10
GND [	18	39	GND
A10 [	19	38	] 1B9
A11 [	20	37	] 1B8
A12 [	21	36	] 1B7
V <sub>CC</sub> [	22	35	]v <sub>cc</sub>
1B1 [	23	34	] 1B6
1B2 [	24	33	] 1B5
GND [	25	32	] GND
1B3 [	26	31	] 1B4
LE2B	27	30	LEA1B
SEL [	28	29	OE1B
			•

Address and/or data information can be stored using the internal storage latches. The latch-enable (LE1B, LE2B, LEA1B, and LEA2B) inputs are used to control data storage. When the latch-enable input is high, the latch is transparent. When the latch-enable input goes low, the data present at the inputs is latched and remains latched until the latch-enable input is returned high.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74ALVCH16260 is characterized for operation from -40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. Widebus, EPIC are trademarks of Texas Instruments.

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### **FUNCTION TABLES**

## B TO A ( $\overline{OEB} = H$ )

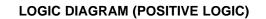
		INP	UTS			OUTPUT
1B	2B	SEL	LE1B	LE2B	OEA	Α
Н	Х	Н	Н	Х	Г	Н
L	Х	Н	Н	Х	L	L
Х	Х	Н	L	Х	L	A <sub>0</sub>
Х	Н	L	Х	Н	L	Н
Х	L	L	Х	Н	L	L
Х	Х	L	Х	L	L	A <sub>0</sub>
Х	Х	Х	Х	Х	Н	Z

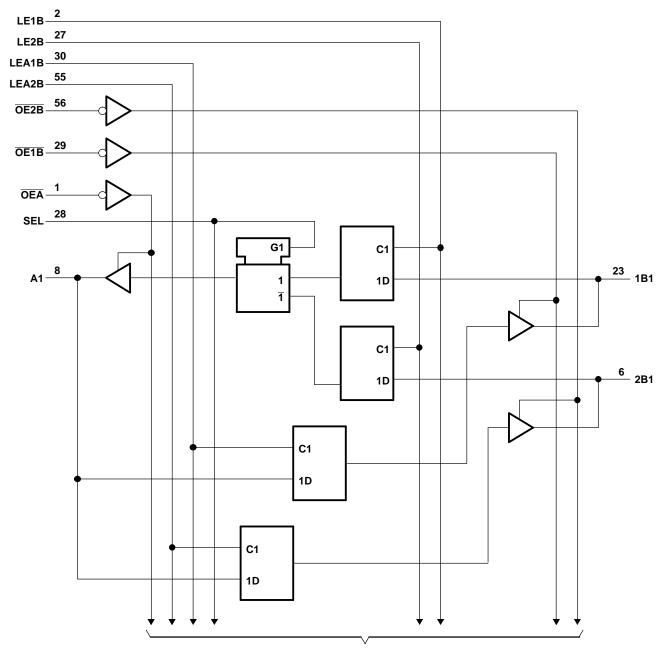
# A TO B (OEA = H)

		INPUTS			OUTI	PUTS
Α	LEA1B	LEA2B	OE1B	OE2B	1B	2B
Н	Н	Н	L	L	Н	Н
L	Н	Н	L	L	L	L
н	Н	L	L	L	н	2B <sub>0</sub>
L	Н	L	L	L	L	2B <sub>0</sub>
н	L	Н	L	L	1B <sub>0</sub>	Н
L	L	Н	L	L	1B <sub>0</sub>	L
Х	L	L	L	L	1B <sub>0</sub>	2B <sub>0</sub>
Х	Х	Х	Н	Н	Z	Z
Х	Х	Х	L	Н	Active	Z
Х	Х	Х	Н	L	Z	Active
Х	Х	Х	L	L	Active	Active



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To 11 Other Channels

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## 

### **ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>**

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V
V		Except I/O ports <sup>(2)</sup>	-0.5	4.6	V
VI	Input voltage range	I/O ports <sup>(2)(3)</sup>	-0.5	V <sub>CC</sub> + 0.5	v
Vo	Output voltage range <sup>(2)(3)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current			±50	mA
	Continuous current through each V <sub>CC</sub> or G	GND		±100	mA
0	$\mathbf{D}_{\mathbf{r}}$ also so the sum of $\mathbf{r}_{\mathbf{r}}$ and $\mathbf{r}_{\mathbf{r}}$	DGG package		81	0000
$\theta_{JA}$	Continuous output current Continuous current through each V <sub>CC</sub> or GI Package thermal impedance <sup>(4)</sup>	DL package		74	°C/W
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) This value is limited to 4.6 V maximum.

(4) The package thermal impedance is calculated in accordance with JESD 51.

## **RECOMMENDED OPERATING CONDITIONS**<sup>(1)</sup>

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage		1.65	3.6	V
		V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65  imes V_{CC}$		
$V_{\text{IH}}$	High-level input voltage	$V_{CC}$ = 2.3 V to 2.7 V	1.7		V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		
		V <sub>CC</sub> = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	
V <sub>IL</sub>	Low-level input voltage	$V_{CC}$ = 2.3 V to 2.7 V		0.7	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8	
VI	Input voltage		0	V <sub>CC</sub>	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.65 V		-4	
	Lich lovel output ourrest	V <sub>CC</sub> = 2.3 V		-12	
I <sub>OH</sub>	High-level output current	$V_{CC} = 2.7 V$		-12	mA
		$V_{CC} = 3 V$		-24	
		V <sub>CC</sub> = 1.65 V		4	
	Low lovel entroit entroit	V <sub>CC</sub> = 2.3 V		12	0
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 2.7 V		12	mA
		$V_{CC} = 3 V$		24	
$\Delta t/\Delta v$	Input transition rise or fall rate			10	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

 All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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### **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP <sup>(1)</sup>	MAX	UNIT
	I <sub>OH</sub> = -100 μA	1.65 V to 3.6 V	V <sub>CC</sub> - 0.2		
	I <sub>OH</sub> = -4 mA	1.65 V	1.2		
	I <sub>OH</sub> = -6 mA	2.3 V	2		
V <sub>OH</sub>		2.3 V	1.7		V
	I <sub>OH</sub> = -12 mA	2.7 V	2.2		
		3 V	2.4		
	I <sub>OH</sub> = -24 mA	3 V	2		
	I <sub>OL</sub> = 100 μA	1.65 V to 3.6 V		0.2	
	I <sub>OL</sub> = 4 mA	1.65 V		0.45	
	I <sub>OL</sub> = 6 mA	2.3 V		0.4	V
V <sub>OL</sub>	1. 10 1	2.3 V		0.7	V
	$I_{OL} = 12 \text{ mA}$	2.7 V		0.4	
	I <sub>OL</sub> = 24 mA	3 V		0.55	
I <sub>I</sub>	$V_{I} = V_{CC} \text{ or } GND$	3.6 V		±5	μA
	V <sub>I</sub> = 0.58 V	1.65 V	25		
	V <sub>I</sub> = 1.07 V	1.65 V	-25		
	V <sub>I</sub> = 0.7 V	2.3 V	45		
I <sub>I(hold)</sub>	V <sub>I</sub> = 1.7 V	2.3 V	-45		μA
	V <sub>I</sub> = 0.8 V	3 V	75		
	V <sub>1</sub> = 2 V	3 V	-75		
	V <sub>I</sub> = 0 to 3.6 V <sup>(2)</sup>	3.6 V		±500	
I <sub>OZ</sub> <sup>(3)</sup>	$V_{O} = V_{CC}$ or GND	3.6 V		±10	μA
I <sub>cc</sub>	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	3.6 V		40	μΑ
Δl <sub>CC</sub>	One input at $V_{CC}$ - 0.6 V, Other inputs at $V_{CC}$ or GND	3 V to 3.6 V		750	μA
C <sub>i</sub> Control input	s $V_I = V_{CC}$ or GND	3.3 V	3.5		pF
C <sub>io</sub> A or B ports	$V_{O} = V_{CC}$ or GND	3.3 V	9		pF

(1) All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ . (2) This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

(3) For I/O ports, the parameter  $I_{\mbox{\scriptsize OZ}}$  includes the input leakage current.

### TIMING REQUIREMENTS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1 through Figure 3)

		V <sub>CC</sub> =	$\begin{array}{c} V_{CC} = 2.5 \ V \\ \pm \ 0.2 \ V \end{array}$		V <sub>CC</sub> = 2.7 V		$V_{CC}$ = 3.3 V ± 0.3 V		UNIT	
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
tw	Pulse duration, LE1B, LE2B, LEA1B, or LEA2B high	(1)		3.3		3.3		3.3		ns
t <sub>su</sub>	Setup time, data before LE1B, LE2B, LEA1B, or LEA2B	(1)		1.4		1.1		1.1		ns
t <sub>h</sub>	Hold time, data after LE1B, LE2B, LEA1B, or LEA2B	(1)		1.6		1.9		1.5		ns

(1) This information was not available at the time of publication.

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### SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1 through Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V	$V_{CC}$ = 2.5 V $\pm$ 0.2 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 1 ± 0.3	UNIT	
	(INFOT)	(001-01)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	
	A or B	B or A	(1)	1	5.4		5.1	1.2	4.3	
t <sub>pd</sub>	LE	A or B	(1)	1	5.6		5.2	1	4.4	ns
	SEL	A	(1)	1	6.9		6.6	1.1	5.6	
t <sub>en</sub>	OE	A or B	(1)	1	6.7		6.4	1	5.4	ns
t <sub>dis</sub>	OE	A or B	(1)	1	5.7		5	1.3	4.6	ns

(1) This information was not available at the time of publication.

## **OPERATING CHARACTERISTICS**

 $T_A = 25^{\circ}C$ 

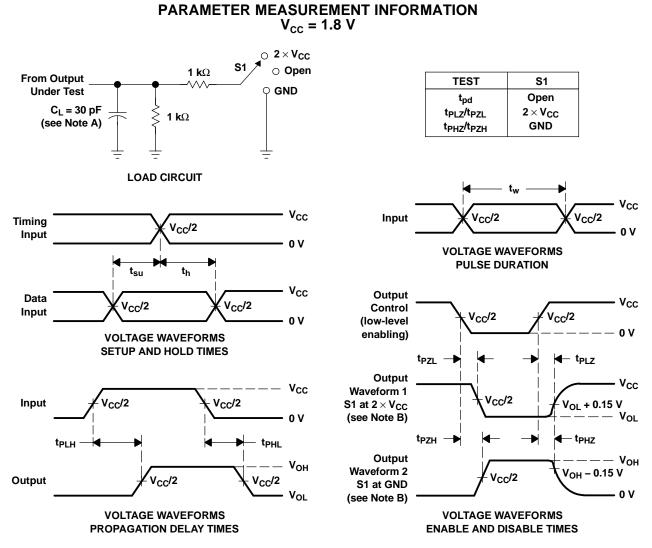
	PARAME	TER	TEST CONDITIONS	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	UNIT
~	Power dissipation	All outputs enabled		(1)	37	41	~F
Cpd	capacitance	All outputs disabled	$C_{L} = 50 \text{ pF}, \text{ f} = 10 \text{ MHz}$	(1)	4	7	рF

(1) This information was not available at the time of publication.

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## SN74ALVCH16260 12-BIT TO 24-BIT MULTIPLEXED D-TYPE LATCH WITH 3-STATE OUTPUTS

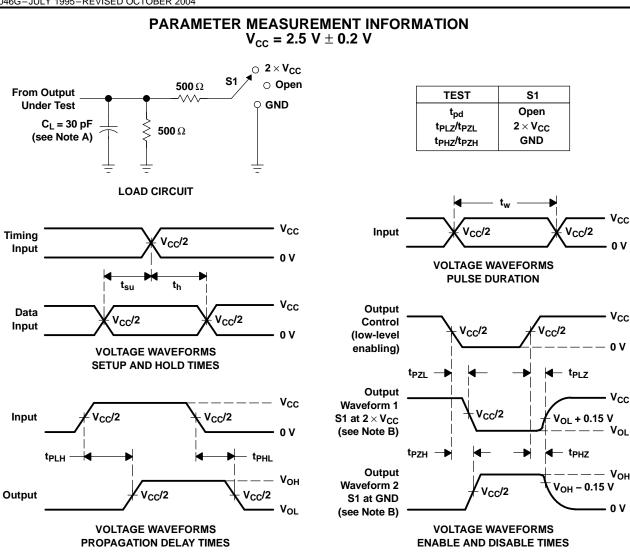
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- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2 ns, t<sub>f</sub>  $\leq$  2 ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

#### Figure 1. Load Circuit and Voltage Waveforms





TEXAS IRUMENTS

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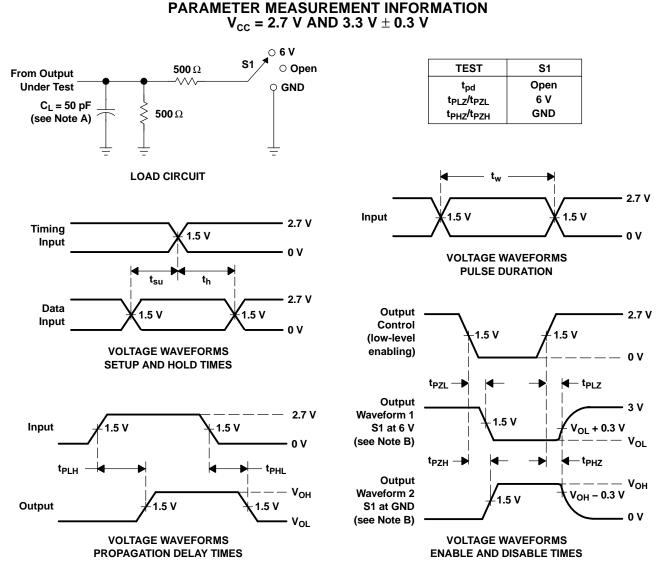
NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
- Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2 ns, t<sub>f</sub>  $\leq$  2 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- D. The outputs are measured one at a
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH} \, \text{and} \, t_{PHL}$  are the same as  $t_{pd}.$

#### Figure 2. Load Circuit and Voltage Waveforms



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NOTES: A.  $C_L$  includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z<sub>Q</sub> = 50 Ω, t<sub>f</sub> ≤ 2.5 ns. t<sub>f</sub> ≤ 2.5 ns.

- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 3. Load Circuit and Voltage Waveforms



10-Dec-2020

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74ALVCH16260DGGR	ACTIVE	TSSOP	DGG	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH16260	Samples
SN74ALVCH16260DL	ACTIVE	SSOP	DL	56	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH16260	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE OPTION ADDENDUM

10-Dec-2020

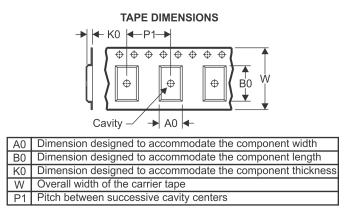
# PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions a	are nominal
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Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALVCH16260DGGR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1



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# PACKAGE MATERIALS INFORMATION

5-Jan-2022



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALVCH16260DGGR	TSSOP	DGG	56	2000	367.0	367.0	45.0



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5-Jan-2022

## TUBE



#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN74ALVCH16260DL	DL	SSOP	56	20	473.7	14.24	5110	7.87

DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
  - This drawing is subject to change without notice. В.
  - Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15). C.
  - D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.



# **PACKAGE OUTLINE**

# **DGG0056A**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not

- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-153.



# DGG0056A

# **EXAMPLE BOARD LAYOUT**

# TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# DGG0056A

# **EXAMPLE STENCIL DESIGN**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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